Monolithic integration of light sources, detectors, memory, and electronics At least four planes of passive photonic waveguides

Both Platforms

Wafer-scale processing Inter-wafer optical links

Memory meeting requirements in Sec. 4.1

Semiconductor Platform

Femtojoule optical receivers with low static power One million III-V light-sources per wafer

integrated with CMOS electronics

Synapses and local plasticity circuits in area 10µm x 10µm

Superconductor Platform

One million III-V or group-IV light sources per wafer

operating at cryogenic temperature

Interface superconducting electronics with

semiconductor light sources

Serial biasing or current recycling

for synapses and neurons

Eight planes of Josephson junctions and transformers per wafer with near-zero cross talk